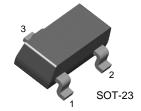


KST2907A

General Purpose Transistor



1. Base 2. Emitter 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-------|-------|
| V_{CBO} | Collector-Base Voltage | -60 | V |
| V _{CEO} | Collector-Emitter Voltage | -60 | V |
| V _{EBO} | Emitter-Base Voltage | -5 | V |
| I _C | Collector Current | -600 | mA |
| P _C | Collector Power Dissipation | 350 | mW |
| T _{STG} | Storage Temperature | 150 | °C |

Electrical Characteristics T_a =25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Max. | Units |
|-----------------------|--|--|-------------------------------|--------------|--------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I_{C} = -10 μ A, I_{E} =0 | -60 | | V |
| BV _{CEO} | * Collector-Emitter Breakdown Voltage | I _C = -10mA, I _B =0 | -60 | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E = -10μA, I _C =0 | -5 | | V |
| I _{CBO} | Collector Cut-off Current | V _{CB} = -50V, I _E =0 | | -0.01 | μΑ |
| h _{FE} | DC Current Gain | V_{CE} = -10V, I_{C} = -0.1mA V_{CE} = -10V, I_{C} = -1.0mA V_{CE} = -10V, I_{C} = -10mA V_{CE} = -10V, I_{C} = -150mA V_{CE} = -10V, I_{C} = -500mA | 75 100 100 100 50 | 300 | |
| V _{CE} (sat) | * Collector-Emitter Saturation Voltage | I _C = -150mA, I _B = -15mA I _C = -500mA, I _B = -50mA | | -0.4 -1.6 | V V |
| V _{BE} (sat) | * Base-Emitter Saturation Voltage | I_C = -150mA, I_B = -15mA I_C = -500mA, I_B = -50mA | | -1.3 -2.6 | V V |
| f _T | Current Gain Bandwidth Product | I _C = -50mA, V _{CE} = -20V f=100MHz | 200 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} = -10V, I _E =0, f=1.0MHz | | 8 | pF |
| t _{ON} | Turn On Time | V_{CC} = -30V, I_{C} = -150mA I_{B1} = -15mA | | 50 | ns |
| t _{OFF} | Turn Off Time | V_{CC} = -6V, I_{C} = -150mA I_{B1} = I_{B2} = -15mA | | 110 | ns |

^{*} Pulse Test: PW≤300μs, Duty Cycle≤2%



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Typical Characteristics

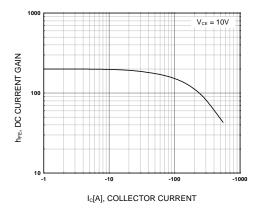


Figure 1. DC current Gain

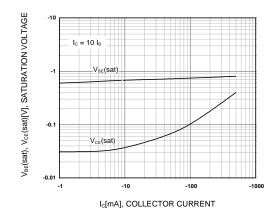


Figure 2. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

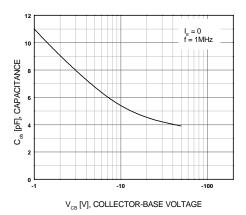


Figure 3. Output Capacitance

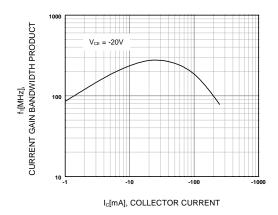
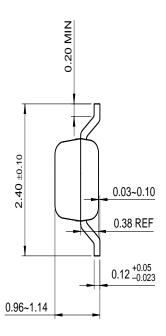


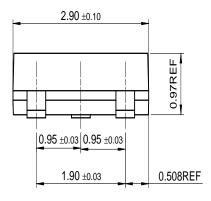
Figure 4. Current Gain Bandwidth Product

Package Demensions

SOT-23







Dimensions in Millimeters

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